TECHNICAL DATA DATA SHEET 4123, REV. A

HERMETIC POWER SCHOTTKY RECTIFIER

Low Reverse Leakage 175 °C Operating Temperature

DESCRIPTION: 60 VOLT, 15 AMP, POWER SCHOTTKY RECTIFIER IN A TO-257 2-LEAD PACKAGE.

MAXIMUM RATINGS

ALL RATINGS ARE @ $T_C = 25$ °C UNLESS OTHERWISE SPECIFIED.

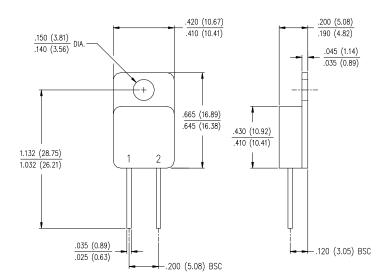
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RATING	SYMBOL	MAX.	UNITS	
PEAK INVERSE VOLTAGE	PIV	60	Volts	
MAXIMUM DC OUTPUT CURRENT (With Cathode Maintained @ T _C =100 °C)	Io	15	Amps	
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT (t=8.3ms, Sine)	I _{FSM}	280	Amps	
MAXIMUM JUNCTION CAPACITANCE (V _r =5V)	Ст	720	pF	
MAXIMUM THERMAL RESISTANCE (Junction to Mounting Surface, Cathode)	$R_{ heta JC}$	2.0	°C/W	
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE	Top/Tstg	-65 to + 175	°C	

ELECTRICAL CHARACTERISTICS

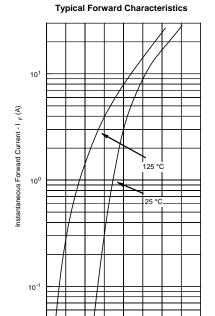
CHARACTERISTIC			
MAXIMUM FORWARD VOLTAGE DROP, Pulsed (I _f = 15 Amps)			
T _J = 25 °C	V_{f}	.80	Volts
T _J = 125 °C	'	.73	
MAXIMUM REVERSE CURRENT (I _r @ 60V PIV)			
T _J = 25 °C	I_r	0.4	mA
T _J = 125 °C		30	

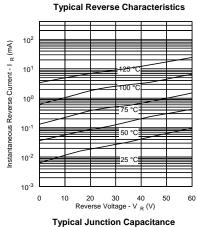
DATA SHEET 4123, REV. A

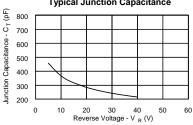
MECHANICAL DIMENSIONS: In Inches / mm



Pin 1: Cathode Pin 2: Anode







Note: Vf curves are for bare die only.

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DATA SHEET 4123, REV. A

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